PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Satoshi SUGAHARA et al.

Application No.: New U.S. National Stage of

PCT/JP2004/000567

Filed: September 2, 2005 Docket No.: 125209

For: FIELD-EFFECT TRANSISTOR WITH SPIN-DEPENDENT TRANSMISSION CHARACTERISTICS AND NON-VOLATILE MEMORY USING THE SAME

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- Relevance of the reference 5 is discussed in the present specification.
- 3. The references 1-4 were cited in the International Search Report. An English language version of the International Search Report is attached for the Examiner's information.
- 4. English language Abstracts of the non-English language references 1-4 are attached hereto.

New U.S. National Stage of PCT/JP2004/000567

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5. A computer-generated English language translation of the following Japanese Patent Publication has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See References 1-4.

Respectfully submitted,

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Date: September 2, 2005

OLIFF & BERRIDGE, PLC P.O. Box 19928 Alexandria, Virginia 22320 Telephone: (703) 836-6400 DEPOSIT ACCOUNT USE
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Sheet 1 of 1

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 125209			APPLICATION NO. New U.S. National Stage of PCT/JP2004/000567			
INFOR	MATIO	ON DISCLOSURE STATEMENT				1				
(Use several sheets if necessary)					APPLICANTS Satoshi SUGAHARA et al.					
					FILING DATE September 2, 2005					
U.S. PATENT DOCUMENTS										
EXAMINER INITIAL		DOCUMENT NUMBER	DATE		NAME			CLASS	SUB CLASS	
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FOREIGN PATENT DOCUMENTS										
		DOCUMENT NUMBER]	DATE	COUNTI	RY		CLASS	SUB CLASS	
	1	JP A 2001-250998 w/abstr. + trans.	09/14/2001		Japan					
	2	JP A 2001-93274 w/abstr. + trans.	04/06/2001		Japan					
	3	JP A 10-284765 w/abstr. + trans.	10/23/1998		Japan					
	4	JP A 2004-111904 w/abstr. + trans.	04/0	08/2004	Japan					
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)										
	5	Inomata, "Present and Future of Magnetic RAM Technology," IEICE Trans. Electron, Vol. E84-C, No. 6, pp. 740-746, June 2001								
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EXAMINER DATE CONSIDERED										
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.										

Date: September 2, 2005